

L Number	Hits	Search Text	DB	Time stamp
1	1412771	passivat\$3 or insulat\$3 or planariz\$5 or overcoat\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/10/17 09:27
2	320161	liquid near6 crystal	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/10/17 09:28
3	3867	(liquid near6 crystal) near6 seal	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/10/17 09:29
4	1	remov\$3 near6 (passivat\$3 or insulat\$3 or planariz\$5 or overcoat\$3) near6 ((liquid near6 crystal) near6 seal)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/10/17 09:31
5	40	349/153 and (remov\$3 near6 (passivat\$3 or insulat\$3 or planariz\$5 or overcoat\$3))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/10/17 09:32

L Number	Hits	Search Text	DB	Time stamp
1	52241	screen near6 printing	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/10/17 10:56
2	87639	glass near6 fiber	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/10/17 10:57
3	39	(screen near6 printing) near6 (glass near6 fiber)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/10/17 10:57
4	4	((screen near6 printing) near6 (glass near6 fiber)) near6 seal	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/10/17 11:05
5	9903	data near6 pad	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/10/17 11:15
6	235469	data near6 line	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/10/17 11:16
7	2	seal near6 (data near6 pad) near6 (data near6 line)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/10/17 11:23
8	12	349/153 and (data near6 pad)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/10/17 11:09
9	73	349/153 and (data near6 line)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/10/17 11:09
10	10	(349/153 and (data near6 pad)) and (349/153 and (data near6 line))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/10/17 11:12
11	754	(data near6 pad) near6 (data near6 line)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/10/17 11:13
12	0	seal near6 ((data near6 pad) near6 (data near6 line))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/10/17 11:13

13	1	seal near20 ((data near6 pad) near6 (data near6 line))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/10/17 11:13
14	1	seal near50 ((data near6 pad) near6 (data near6 line))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/10/17 11:13
15	6802	gate near6 pad	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/10/17 11:16
16	85491	gate near6 line	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/10/17 11:18
17	1	seal near6 (gate near6 pad) near6 (gate near6 line)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/10/17 11:26
18	77	seal near6 pad near6 line	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/10/17 11:19
19	3	349\$.ccls. and (seal near6 pad near6 line)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/10/17 11:19
20	4	seal near20 (data near6 pad) near20 (data near6 line)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/10/17 11:23
21	2	seal near20 (gate near6 pad) near20 (gate near6 line)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/10/17 11:26

L Number	Hits	Search Text	DB	Time stamp
1	36947	storage near6 capacitor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/10/17 12:15
2	27858	gate near6 insulating near6 layer	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/10/17 12:16
3	219712	semiconductor near6 layer	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/10/17 12:18
4	1516	auxiliary near6 capacit\$5 near6 electrode	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/10/17 12:19
5	1412771	passivat\$3 or insulat\$3 or planariz\$5 or overcoat\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/10/17 12:21
6	176	pixel near6 (contact\$3 or connect\$3) near6 (auxiliary near6 capacit\$5 near6 electrode)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/10/17 12:56
7	7	(storage near6 capacitor) and (gate near6 insulating near6 layer) and (semiconductor near6 layer) and (auxiliary near6 capacit\$5 near6 electrode) and (passivat\$3 or insulat\$3 or planariz\$5 or overcoat\$3) and (pixel near6 (contact\$3 or connect\$3) near6 (auxiliary near6 capacit\$5 near6 electrode))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/10/17 12:32
8	2	6624857.did.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/10/17 12:33
9	23	(pixel near6 (contact\$3 or connect\$3) near6 (auxiliary near6 capacit\$5 near6 electrode)) and (storage near6 capacitor)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/10/17 12:35
10	57	(gate near6 insulating near6 layer) near6 (overlay\$5 or overlap\$5 or cover\$5) near6 (storage near6 capacitor)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/10/17 12:36
11	0	(pixel near6 (contact\$3 or connect\$3) near6 (auxiliary near6 capacit\$5 near6 electrode)) and ((gate near6 insulating near6 layer) near6 (overlay\$5 or overlap\$5 or cover\$5) near6 (storage near6 capacitor))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/10/17 12:36
12	0	(pixel near6 (contact\$3 or connect\$3) near6 (auxiliary near6 capacit\$5 near6 electrode)) near ((gate near6 insulating near6 layer) near6 (overlay\$5 or overlap\$5 or cover\$5) near6 (storage near6 capacitor))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/10/17 12:36

13	274	(gate near6 insulating near6 layer) near6 (storage near6 capacitor)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/10/17 12:37
14	1	(pixel near6 (contact\$3 or connect\$3) near6 (auxiliary near6 capacit\$5 near6 electrode)) and ((gate near6 insulating near6 layer) near6 (storage near6 capacitor))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/10/17 12:38
15	96189	capacit\$5 near6 electrode	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/10/17 12:39
16	1425	pixel near6 (contact\$3 or connect\$3) near6 (capacit\$5 near6 electrode)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/10/17 12:40
17	22	((gate near6 insulating near6 layer) near6 (overlay\$5 or overlap\$5 or cover\$5) near6 (storage near6 capacitor)) and (pixel near6 (contact\$3 or connect\$3) near6 (capacit\$5 near6 electrode))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/10/17 12:40
18	3	pixel near6 (contact\$3 or connect\$3) near6 side near6 (auxiliary near6 capacit\$5 near6 electrode)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/10/17 12:54
19	59	(pixel near6 (contact\$3 or connect\$3) near6 (auxiliary near6 capacit\$5 near6 electrode)) and @py<2000	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/10/17 12:57

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